

Silicon Tuning Diodes

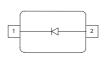
- High capacitance ratio
- High Q hyperabrupt tuning diode
- Low series resistance
- Designed for low tuning voltage operation for VCO's in mobile communications equipment
- Very low capacitance spread
- Pb-free (RoHS compliant) package 1)
- Qualified according AEC Q101





BBY66-02V

BBY66-05 BBY66-05W





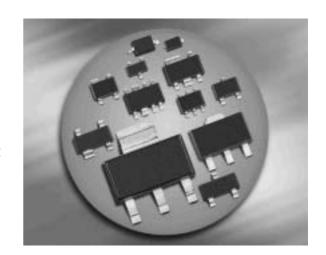
Туре	Package	Configuration	L S(nH)	Marking
BBY66-02V	SC79	single	0.6	h
BBY66-05	SOT23	common cathode	1.8	O1s / O2s**
BBY66-05W	SOT323	common cathode	1.4	OBs

^{**}For differences see next page Capacitance groups

Maximum Ratings at $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Value	Unit					
Diode reverse voltage	V_{R}	12	V					
Forward current	I _F	50	mA					
Operating temperature range	T _{op}	-55 150	°C					
Storage temperature	$T_{ m stg}$	-55 150						

¹Pb-containing package may be available upon special request





Electrical Characteristics at $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol		Unit		
		min.	typ.	max.	
DC Characteristics	•				
Reverse current	I_{R}				nA
V _R = 10 V		-	-	20	
$V_{R} = 10 \text{ V}, T_{A} = 65 ^{\circ}\text{C}$		-	-	200	
AC Characteristics					
Diode capacitance ¹⁾	C _T				pF
$V_{R} = 1 \text{ V}, f = 1 \text{ MHz}$		66	68.7	71.5	
$V_{R} = 2 \text{ V}, f = 1 \text{ MHz}$		33	35.4	38	
$V_{R} = 3 \text{ V}, f = 1 \text{ MHz}$		19.7	20.95	22.2	
$V_{R} = 4.5 \text{ V}, f = 1 \text{ MHz}$		12	12.7	13.5	
Capacitance ratio	C _{T1} /C _{T4.5}	5	5.41	-	
$V_{R} = 1 \text{ V}, V_{R} = 4.5 \text{ V}$					
Series resistance	r _S	-	0.25	0.4	Ω
$V_{R} = 1 \text{ V}, f = 470 \text{ MHz}$					

¹Capacitance groups at 1V, coded 01; 02 (only BBY66-05)

 $C_{\text{T}}/\text{groups}$ 01 02

 C_{1V} min 66pF 68.5pF C_{1V} max 69pF 71.5pF

Deliveries contain either C_{T} group 01 or group 02 (marked on reel).

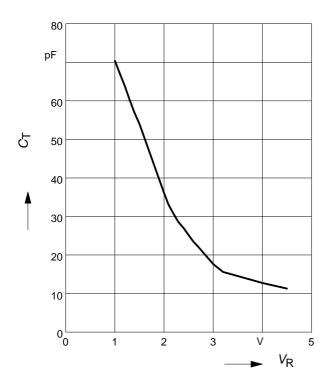
No direct order of C_T groups possible

2 2007-04-20

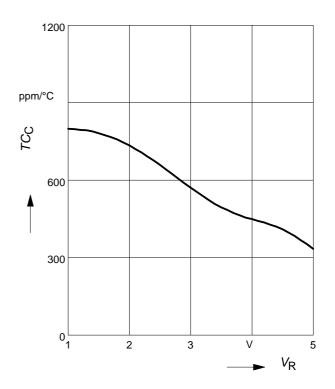


Diode capacitance $C_T = f(V_R)$

f = 1MHz

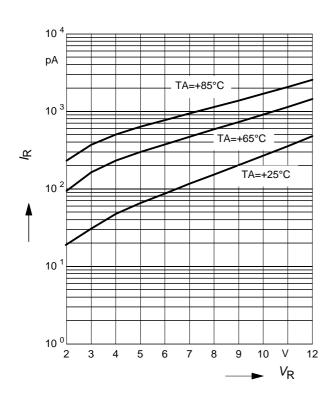


Temperature coefficient of the diode capacitance $T_{Cc} = f(V_R)$



Reverse current $I_R = f(V_R)$

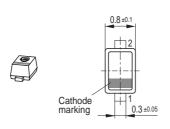
 T_A = Parameter

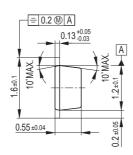


3 2007-04-20



Package Outline

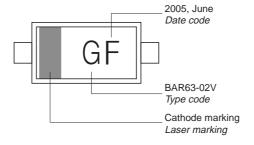




Foot Print



Marking Layout (Example)

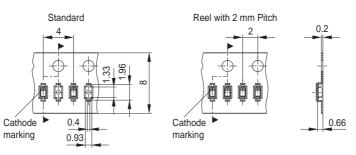


Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel

Reel ø180 mm = 8.000 Pieces/Reel (2 mm Pitch)

Reel ø330 mm = 10.000 Pieces/Reel



4



Date Code marking for discrete packages with one digit (SCD80, SC79, SC751) CES-Code

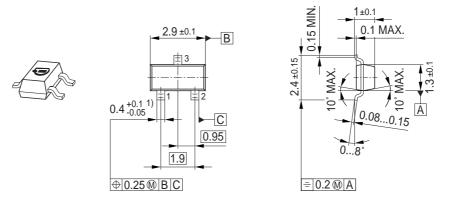
Month	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014
01	а	р	Α	Р	а	р	Α	Р	а	р	Α	Р
02	b	q	В	Q	b	q	В	Q	b	q	В	Q
03	С	r	С	R	С	r	С	R	С	r	С	R
04	d	S	D	S	d	S	D	S	d	S	D	S
05	е	t	Е	Т	е	t	Е	Т	е	t	Е	Т
06	f	u	F	U	f	u	F	U	f	u	F	U
07	g	٧	G	V	g	٧	G	V	g	٧	G	V
08	h	Х	Η	Х	h	Х	Н	Х	h	Х	Η	Х
09	j	у	7	Υ	j	у	7	Υ	j	у	J	Υ
10	k	Z	K	Z	k	Z	K	Z	k	Z	K	Z
11	I	2	L	4	ı	2	L	4	I	2	L	4
12	n	3	N	5	n	3	N	5	n	3	N	5

¹⁾ New Marking Layout for SC75, implemented at October 2005.

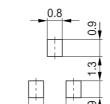
5 2007-04-20



Package Outline

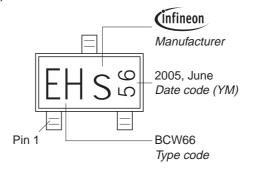


Foot Print



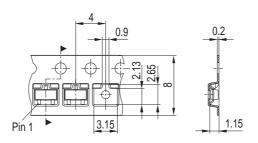
1) Lead width can be 0.6 max. in dambar area

Marking Layout (Example)



Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel

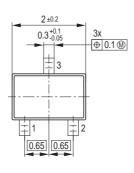


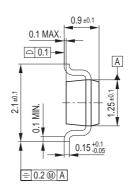
6



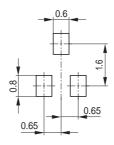
Package Outline



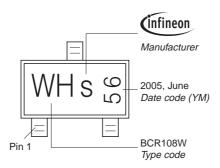




Foot Print

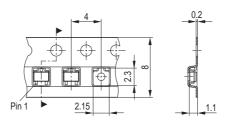


Marking Layout (Example)



Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel





Edition 2006-02-01
Published by
Infineon Technologies AG
81726 München, Germany
© Infineon Technologies AG 2007.
All Rights Reserved.

Attention please!

The information given in this dokument shall in no event be regarded as a guarantee of conditions or characteristics ("Beschaffenheitsgarantie"). With respect to any examples or hints given herein, any typical values stated herein and/or any information regarding the application of the device, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation warranties of non-infringement of intellectual property rights of any third party.

Information

For further information on technology, delivery terms and conditions and prices please contact your nearest Infineon Technologies Office (www.infineon.com).

Warnings

Due to technical requirements components may contain dangerous substances. For information on the types in question please contact your nearest Infineon Technologies Office.

Infineon Technologies Components may only be used in life-support devices or systems with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system, or to affect the safety or effectiveness of that device or system.

Life support devices or systems are intended to be implanted in the human body, or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.

8

2007-04-20

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Varactor Diodes category:

Click to view products by Infineon manufacturer:

Other Similar products are found below:

MA46H201-1056 MAVR-001330-12790T MVAM108 SMV1233-079 SVC704-TL-E SVC710-TL-E ISV324TPH3F MAVR-0000830287AT MAVR-044769-12790T SVC270-TL-E RKV501KJ#R1 MA46H204-1056 MA46H202-1088 MA46H202-1056 MA46H203-1088
MA46H203-1056 MA46H120 MA46H070-1056 ISV282(TPH3,F) SMV1275-079LF SVC272-TL-E GC2510-17 MAVR-044769-02870T
MGV1252208052X MAVR-001350-12790T SMV1251-040LF MX1977 KVX38S2-23-0 GC1213-23-0 GC15006-152 MA46603-276
SMVA1253-079LF MGV125-08-0805-2 MAVR-000079-0287FT MA46H072-1056 MA46H071-1056 MAVR-000120-12030P
BB844E6327HTSA1 BB535E7904HTSA1 BBY5303WE6327HTSA1 BBY5802VH6327XTSA1 BBY6602VH6327XTSA1
ISV281(TPH3,F) BBY5502VH6327XTSA1 BB640E6327HTSA1 BBY40.215 ISV277TPH3F ISV310TPH3F MAVR-000250-11410T
IS2638